



100V PNP MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

Features

- BV_{CEO} > -100V
- I_C = -5A High Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < -90mV @ -1A
- $R_{SAT} = 60m\Omega$ for a Low Equivalent On-Resistance
- h_{FE} Specified Up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Application

- Motor Driving
- Line Switching
- High Side Switches
- Subscriber Line Interface Cards (SLIC)

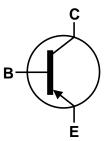
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.112 grams (Approximate)

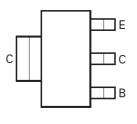
SOT223



Top View



Device Symbol



Top View Pin-Out

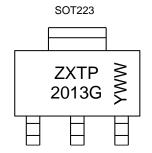
Ordering Information (Note 4)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|----------|--------------------|-----------------|-------------------|
| ZXTP2013GTA | AEC-Q101 | ZXTP2013 | 7 | 12 | 1,000 |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



ZXTP 2013G = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -140 | V |
| Collector-Emitter Voltage | V _{CEO} | -100 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | Ic | -5 | Α |
| Peak Pulse Current | I _{CM} | -10 | Α |

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|----------------------------------|-------------|------------|
| Power Dissipation (Note 5) Linear Derating Factor | P _D | 3.0 24 | W mW/°C |
| Power Dissipation (Note 6) Linear Derating Factor | P _D | 1.6 12.8 | W mW/°C |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{	heta JA}$ | 42 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 6) | $R_{	heta JA}$ | 78 | °C/W |
| Thermal Resistance Junction to Lead (Note 7) | R _{θJL} | 10.48 | °C/W |
| Thermal Resistance Junction to Case (Note 8) | R _{0JC} | 13.8 | °C/W |
| Operating and Storage Temperature Range | T _J ,T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 9)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

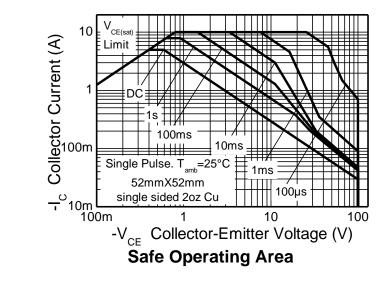
Notes:

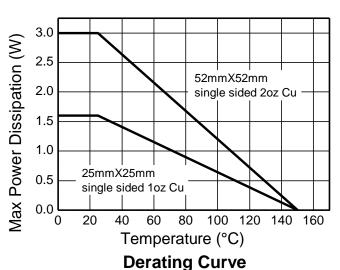
- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 8. Thermal resistance from junction to top of the case.
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

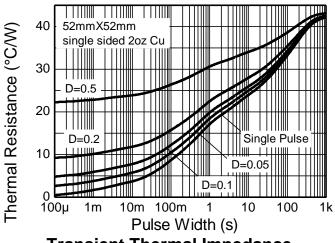


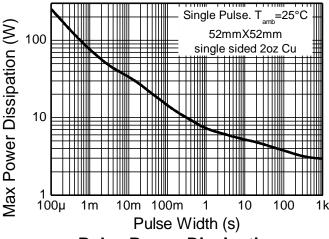


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation

May 2015

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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|---------------------------|--------|----------|-------------|----------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | -140 | -160 | _ | V | $I_C = -100 \mu A$ |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CER} | -140 | -160 | _ | V | $I_C = -1\mu A, R_B \le 1k\Omega$ |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | -100 | -115 | _ | V | $I_C = -1mA$ |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.1 | _ | V | I _E = -100μA |
| Collector Cut-Off Current | I _{CBO} | _ _ | < 1 — | -20 -500 | nA nA | V _{CB} = -100V V _{CB} = -100V, T _A = +100°C |
| Collector Cut-Off Current | I _{CER} R≤1kΩ | _ _ | < 1 — | -20 -500 | nA nA | V _{CB} = -100V V _{CB} = -100V, T _A = +100°C |
| Emitter Cut-Off Current | I _{EBO} | _ | < 1 | -10 | nA | V _{EB} = -6V |
| | | 100 | 250 | _ | | $I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$ |
| | | 100 | 200 | 300 | | I _C = -1A, V _{CE} = -1V |
| DC Current Transfer Static Ratio (Note 10) | h _{FE} | 25 | 50 | _ | _ | I _C = -3A, V _{CE} = -1V |
| | | 15 | 30 | _ | | I _C = -4A, V _{CE} = -1V |
| | | _ | 5 | _ | | $I_C = -10A$, $V_{CE} = -1V$ |
| | VCE(SAT) | _ | -20 | -30 | mV | $I_C = -100 \text{mA}, I_B = -10 \text{mA}$ |
| Collector Emitter Coturation Voltage (Note 10) | | _ | -70 | -90 | | $I_C = -1A$, $I_B = -100mA$ |
| Collector-Emitter Saturation Voltage (Note 10) | | _ | -120 | -150 | | $I_C = -2A$, $I_B = -200mA$ |
| | | _ | -240 | -340 | | $I_C = -4A$, $I_B = -400mA$ |
| Base-Emitter Saturation Voltage (Note 10) | V _{BE(SAT)} | _ | -985 | -1,100 | mV | $I_C = -4A$, $I_B = -400mA$ |
| Base-Emitter Turn-On Voltage (Note 10) | V _{BE(ON)} | _ | -920 | -1,050 | mV | $I_C = -4A$, $V_{CE} = -1V$ |
| Transitional Frequency (Note 10) | f _T | _ | 125 | _ | MHz | I _C = -100mA, V _{CE} = -10V, f = 50MHz |
| Output Capacitance | C _{obo} | _ | 42 | _ | pF | V _{CB} = -10V, f = 1MHz |
| Switching Time | ton | _ | 42 | _ | no | $V_{CC} = -50V, I_{C} = -1A,$ |
| Switching Time | toff | _ | 540 | _ | ns | $I_{B1} = -I_{B2} = -100 \text{mA}$ |

Note:

10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



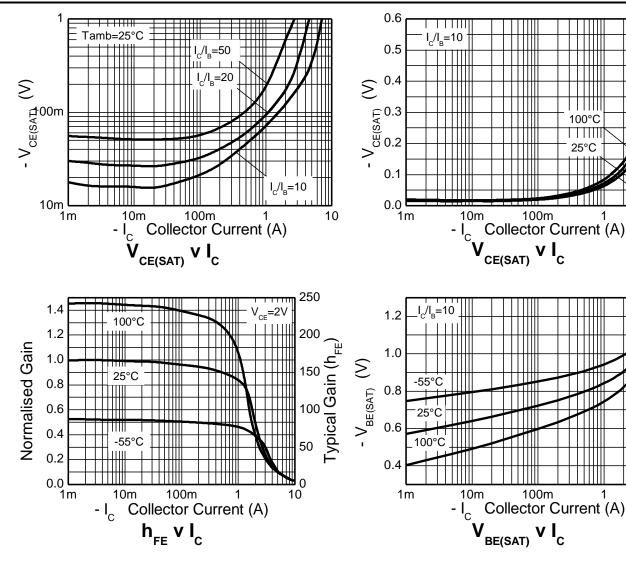


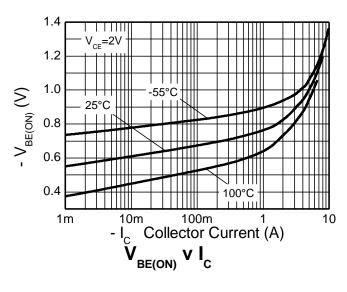
100°C 25°C

10

10

Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

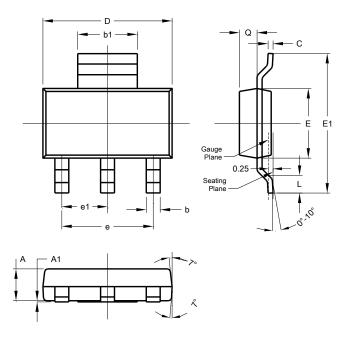






Package Outline Dimensions

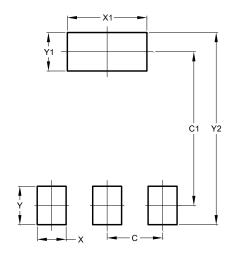
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT223 | | | | | |
|----------------------|-------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1.55 | 1.65 | 1.60 | | |
| A1 | 0.010 | 0.15 | 0.05 | | |
| b | 0.60 | 0.80 | 0.70 | | |
| b1 | 2.90 | 3.10 | 3.00 | | |
| С | 0.20 | 0.30 | 0.25 | | |
| D | 6.45 | 6.55 | 6.50 | | |
| Е | 3.45 | 3.55 | 3.50 | | |
| E1 | 6.90 | 7.10 | 7.00 | | |
| е | - | - | 4.60 | | |
| e1 | - | - | 2.30 | | |
| L | 0.85 | 1.05 | 0.95 | | |
| Q | 0.84 | 0.94 | 0.89 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.30 |
| C1 | 6.40 |
| X | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





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